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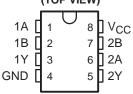
PERIPHERAL DRIVERS FOR HIGH-CURRENT SWITCHING AT VERY HIGH SPEEDS

- Characterized for Use to 300 mA
- High-Voltage Outputs
- No Output Latch-Up at 20 V (After Conducting 300 mA)
- High-Speed Switching
- Circuit Flexibility for Varied Applications
- TTL-Compatible Diode-Clamped Inputs
- Standard Supply Voltages
- Plastic DIP (P) With Copper Lead Frame Provides Cooler Operation and Improved Reliability
- Package Options Include Plastic Small-Outline Packages, Ceramic Chip Carriers, and Standard Plastic and Ceramic 300-mil DIPs

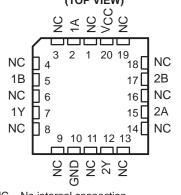
DEVICE	LOGIC OF COMPLETE CIRCUIT	PACKAGES								
SN55451B	AND	FK, JG								
SN55452B	NAND	JG								
SN55453B	OR	FK, JG								
SN55454B	NOR	JG								
SN75451B	AND	D, P								
SN75452B	NAND	D, P								
SN75453B	OR	D, P								
SN75454B	NOR	D, P								

SUMMARY OF DEVICES

SN55451B, SN55452B, SN55453B, SN55454B . . . JG PACKAGE SN75451B, SN75452B, SN75453B, SN75454B . . . D OR P PACKAGE (TOP VIEW)







NC - No internal connection

description

The SN55451B through SN55454B and SN75451B through SN75454B are dual peripheral drivers designed for use in systems that employ TTL logic. This family is functionally interchangeable with and replaces the SN75450 family and the SN75450A family devices manufactured previously. The speed of the devices is equal to that of the SN75450 family, and the parts are designed to ensure freedom from latch-up. Diode-clamped inputs simplify circuit design. Typical applications include high-speed logic buffers, power drivers, relay drivers, lamp drivers, MOS drivers, line drivers, and memory drivers.

The SN55451B/SN75451B, SN55452B/SN75452B, SN55453B/SN75453B, and SN55454B/SN75454B are dual peripheral AND, NAND, OR, and NOR drivers, respectively (assuming positive logic), with the output of the logic gates internally connected to the bases of the npn output transistors.

The SN55' drivers are characterized for operation over the full military range of -55° C to 125° C. The SN75' drivers are characterized for operation from 0° C to 70° C.



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

		SN55'	SN75'	UNIT		
Supply voltage, V _{CC} (see Note 1)		7	7	V		
Input voltage, VI		5.5	5.5	V		
Inter-emitter voltage (see Note 2)	5.5	5.5	V			
Off-state output voltage, VO	30	30	V			
Continuous collector or output current, IOK (see Note 3)	400	400	mA			
Peak collector or output current, II (t_W \leq 10 ms, duty cycle \leq 50%, s	ee Note 4)	500	500	mA		
Continuous total power dissipation		See Diss	See Dissipation Rating Table			
Operating free-air temperature range, TA		-55 to 125	0 to 70	°C		
Storage temperature range, T _{Stg}		-65 to 150	-65 to 150	°C		
Case temperature for 60 seconds	ds FK package 260			°C		
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds	JG package	300		°C		
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	D or P package		260	°C		

NOTES: 1. Voltage values are with respect to network GND, unless otherwise specified.

2. This is the voltage between two emitters of a multiple-emitter transistor.

3. This value applies when the base-emitter resistance (R_{BF}) is equal to or less than 500 Ω .

4. Both halves of these dual circuits may conduct rated current simultaneously; however, power dissipation averaged over a short time interval must fall within the continuous dissipation rating.

DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 125°C POWER RATING
D	725 mW	5.8 mW/°C	464 mW	—
FK	1375 mW	11.0 mW/°C	880 mW	275 mW
JG	1050 mW	8.4 mW/°C	672 mW	210 mW
Р	1000 mW	8.0 mW/°C	640 mW	_

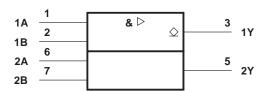
recommended operating conditions

		SN55'			SN75'		UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}	4.5	5	5.5	4.75	5	5.25	V
High-level input voltage, V _{IH}	2			2			V
Low-level input voltage, VIL			0.8			0.8	V
Operating free-air temperature, T _A	-55		125	0		70	°C



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logic symbol[†]

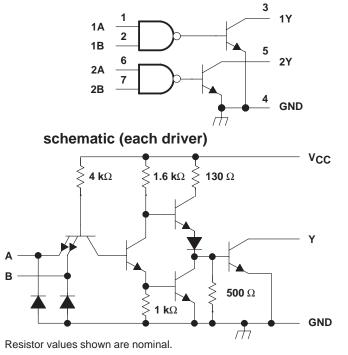


[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC publication 617-12.

Pin numbers shown are for the D, JG, and P packages.

F	FUNCTION TABLE (each driver)										
Α	В	Y									
L	L	L (on state)									
L	н	L (on state)									
Н	L	L (on state)									
Н	Н	H (off state)									
	e logic: AB or										

logic diagram (positive logic)



electrical characteristics over recommended operating free-air temperature range

	PARAMETER	TEAT OON		S	N55451E	3	S	N75451E	3	UNIT
	PARAMETER	TESTCON	TEST CONDITIONS [‡]		TYP§	MAX	MIN	TYP§	MAX	UNIT
VIK	Input clamp voltage	$V_{CC} = MIN,$	lj = -12 mA		-1.2	-1.5		-1.2	-1.5	V
Max		$V_{CC} = MIN,$ $I_{OL} = 100 \text{ mA}$	V _{IL} = 0.8 V,		0.25	0.5		0.25	0.4	V
V _{OL} L	Low-level output voltage	$V_{CC} = MIN,$ $I_{OL} = 300 \text{ mA}$	V _{IL} = 0.8 V,		0.5	0.8		0.5	0.7	V
ЮН	High-level output current	$V_{CC} = MIN,$ $V_{OH} = 30 V$	V _{IH} = MIN,			300			100	μΑ
Ц	Input current at maximum input voltage	$V_{CC} = MAX,$	Vj = 5.5 V			1			1	mA
Ιн	High-level input current	$V_{CC} = MAX,$	V _I = 2.4 V			40			40	μA
Ι _{ΙL}	Low-level input current	V _{CC} = MAX,	$V_{ } = 0.4 V$		-1	-1.6		-1	-1.6	mA
ІССН	Supply current, outputs high	$V_{CC} = MAX,$	V _I = 5 V		7	11		7	11	mA
ICCL	Supply current, outputs low	V _{CC} = MAX,	$V_{I} = 0$		52	65		52	65	mA

[‡] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions. § All typical values are at V_{CC} = 5 V, T_A = 25°C.

switching characteristics, V_{CC} = 5 V, T_A = 25°C

	PARAMETER		TEST CO	MIN	ТҮР	MAX	UNIT	
^t PLH	Propagation delay time, low-to-high-level	output				18	25	
^t PHL	Propagation delay time, high-to-low-level	n delay time, high-to-low-level output		C _L = 15 pF,		18	25	-
^t TLH	Transition time, low-to-high-level output	ition time, low-to-high-level output		See Figure 1		5	8	ns
t THL	Transition time, high-to-low-level output]			7	12	
Val	High lovel output voltage offer switching	SN55451B	V _S = 20 V,	l _O ≈ 300 mA,		Vg-6.5		mV
∨он	High-level output voltage after switching	SN75451B	See Figure 2	-	Vg-6.5			IIIV



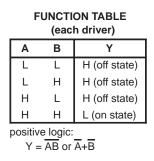
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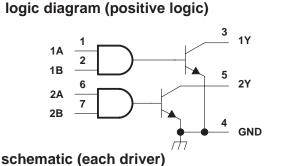
logic symbol[†]

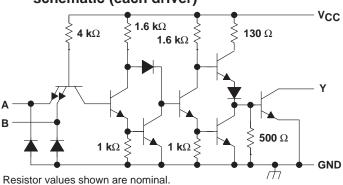


[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC publication 617-12.

Pin numbers shown are for the D, JG, and P packages.







electrical characteristics over recommended operating free-air temperature range

Α

	DADAMETED	TEAT OON		5	SN55452E	3	S	N75452E	3	UNIT
	PARAMETER	TEST CONDITIONS [‡]		MIN	TYP§	MAX	MIN	TYP§	MAX	UNIT
VIK	Input clamp voltage	$V_{CC} = MIN,$	$I_{I} = -12 \text{ mA}$		-1.2	-1.5		-1.2	-1.5	V
Vei		$V_{CC} = MIN,$ $I_{OL} = 100 \text{ mA}$	$V_{IH} = MIN,$		0.25	0.5		0.25	0.4	V
V _{OL} Low-level output voltage	$V_{CC} = MIN,$ $I_{OL} = 300 \text{ mA}$	$V_{IH} = MIN,$		0.5	0.8		0.5	0.7	V	
ЮН	High-level output current	V _{CC} = MIN, V _{OH} = 30 V	V _{IL} = 0.8 V,			300			100	μA
Ц	Input current at maximum input voltage	$V_{CC} = MAX,$	$V_{I} = 5.5 V$			1			1	mA
Чн	High-level input current	$V_{CC} = MAX,$	V _I = 2.4 V			40			40	μA
ЧL	Low-level input current	$V_{CC} = MAX,$	V _I = 0.4 V		-1.1	-1.6		-1.1	-1.6	mA
ІССН	Supply current, outputs high	V _{CC} = MAX,	V _I = 0		11	14		11	14	mA
ICCL	Supply current, outputs low	$V_{CC} = MAX,$	V _I = 5 V		56	71		56	71	mA

[‡] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions. § All typical values are at V_{CC} = 5 V, T_A = 25°C.

switching characteristics, $V_{CC} = 5 V$, $T_A = 25^{\circ}C$

	PARAMETER			TEST CONDITIONS			MAX	UNIT
t _{PLH}	Propagation delay time, low-to-high-level output					26	35	
^t PHL	Propagation delay time, high-to-low-level output		I _O ≈ 200 mA,			24	35	-
^t TLH	Transition time, low-to-high-level output	Transition time, low-to-high-level output		See Figure 1		5	8	ns
^t THL	Transition time, high-to-low-level output					7	12	
Val	High lovel output voltage ofter outphing	SN55452B	V _S = 20 V,	l _O ≈ 300 mA,		Vg-6.5		mV
∨он	High-level output voltage after switching	SN75452B	See Figure 2	-	V _S -6.5			mv



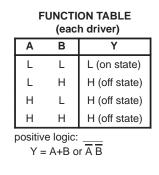
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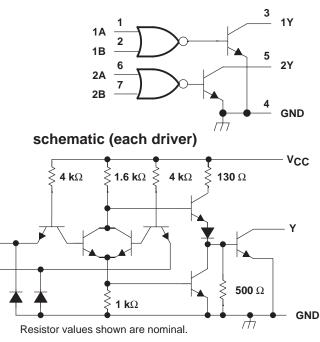
logic symbol[†]



[†]This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC publication 617-12.

Pin numbers shown are for the D, JG, and P packages.





logic diagram (positive logic)

electrical characteristics over recommended operating free-air temperature range

B

	DADAMETER	7507.000		5	SN55453E	3	5	SN75453E	3	LINUT
	PARAMETER	TESTCON	TEST CONDITIONS [‡]		TYP§	MAX	MIN	TYP§	MAX	UNIT
VIK	Input clamp voltage	$V_{CC} = MIN,$	l _l = –12 mA		-1.2	-1.5		-1.2	-1.5	V
) ($V_{CC} = MIN,$ $I_{OL} = 100 \text{ mA}$	V _{IL} = 0.8 V,		0.25	0.5		0.25	0.4	V
VOL	Low-level output voltage	$V_{CC} = MIN,$ $I_{OL} = 300 \text{ mA}$	V _{IL} = 0.8 V,		0.5	0.8		0.5	0.7	v
ЮН	High-level output current	V _{CC} = MIN, V _{OH} = 30 V	VIH = MIN,			300			100	μΑ
lj	Input current at maximum input voltage	$V_{CC} = MAX,$	Vj = 5.5 V			1			1	mA
IIH	High-level input current	$V_{CC} = MAX,$	V _I = 2.4 V			40			40	μΑ
۱ _{IL}	Low-level input current	$V_{CC} = MAX,$	V _I = 0.4 V		-1	-1.6		-1	-1.6	mA
Іссн	Supply current, outputs high	$V_{CC} = MAX,$	V _I = 5 V		8	11		8	11	mA
ICCL	Supply current, outputs low	V _{CC} = MAX,	V _I = 0		54	68		54	68	mA

[‡] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions. § All typical values are at V_{CC} = 5 V, T_A = 25° C.

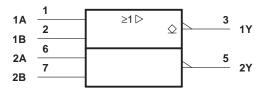
switching characteristics, $V_{CC} = 5 V$, $T_A = 25^{\circ}C$

	PARAMETER			TEST CONDITIONS			MAX	UNIT
^t PLH	Propagation delay time, low-to-high-level	output				18	25	
^t PHL	Propagation delay time, high-to-low-level	ay time, high-to-low-level output		CL = 15 pF,		18	25	50
^t TLH	Transition time, low-to-high-level output			See Figure 1		5	8	ns
^t THL	Transition time, high-to-low-level output		1			7	12	
Varia	Ligh lovel output veltage ofter outphing	SN55453B	V _S = 20 V,	l _O ≈ 300 mA,		V _S -6.5		
∨он	High-level output voltage after switching	SN75453B	See Figure 2		Vg-6.5			mV



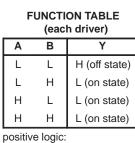
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logic symbol[†]

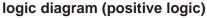


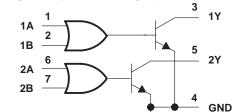
[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC publication 617-12.

Pin numbers shown are for the D, JG, and P packages.



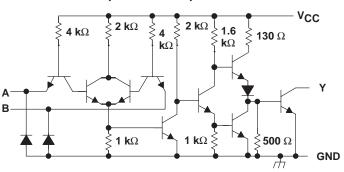
 $Y = \overline{A+B} \text{ or } \overline{AB}$





h

schematic (each driver)



Resistor values shown are nominal.

electrical characteristics over recommended operating free-air temperature range

	PARAMETER	TEST CON	DITIONS	S	N55454E	3	S	N75454E	3	UNIT
	PARAMETER	TEST CON	TEST CONDITIONS [‡]		TYP§	MAX	MIN	TYP§	MAX	UNIT
VIK	Input clamp voltage	$V_{CC} = MIN,$	lj = -12 mA		-1.2	-1.5		-1.2	-1.5	V
Vei		$V_{CC} = MIN,$ $I_{OL} = 100 \text{ mA}$	VIH = MIN,		0.25	0.5		0.25	0.4	V
VOL	Low-level output voltage	$V_{CC} = MIN,$ $I_{OL} = 300 \text{ mA}$	VIH = MIN,		0.5	0.8		0.5	0.7	V
ЮН	High-level output current	V _{CC} = MIN, V _{OH} = 30 V	VIL = 0.8 V,			300			100	μA
Ιį	Input current at maximum input voltage	$V_{CC} = MAX,$	Vj = 5.5 V			1			1	mA
Iн	High-level input current	$V_{CC} = MAX,$	VI = 2.4 V			40			40	μA
١ _L	Low-level input current	$V_{CC} = MAX,$	V _I = 0.4 V		-1	-1.6		-1	-1.6	mA
Іссн	Supply current, outputs high	V _{CC} = MAX,	V _I = 0		13	17		13	17	mA
ICCL	Supply current, outputs low	V _{CC} = MAX,	V _I = 5 V		61	79		61	79	mA

[‡] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

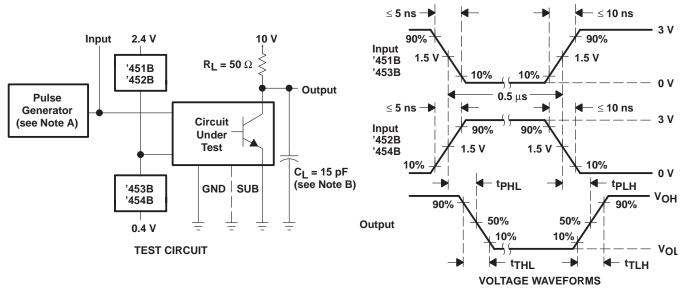
§ All typical values are at V_{CC} = 5 V, T_A = 25°C.

switching characteristics, $V_{CC} = 5 V$, $T_A = 25^{\circ}C$

	PARAMETER	TEST CO	NDITIONS	MIN	TYP	MAX	UNIT	
^t PLH	PLH Propagation delay time, low-to-high-level output					27	35	
^t PHL	tPHL Propagation delay time, high-to-low-level output			CL = 15 pF,		24	35	
^t TLH	Transition time, low-to-high-level output	R _L = 50 Ω,	See Figure 1		5	8	ns	
^t THL	Transition time, high-to-low-level output				7	12		
V	High-level output voltage after switching	SN55454B	V _S = 20 V,	I _O ≈ 300 mA,		Vg-6.5		mV
VOH	High-level output voltage after switching	SN75454B	See Figure 2		V _S -6.5			IIIV



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PARAMETER MEASUREMENT INFORMATION

NOTES: A. The pulse generator has the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω . B. C_L includes probe and jig capacitance.

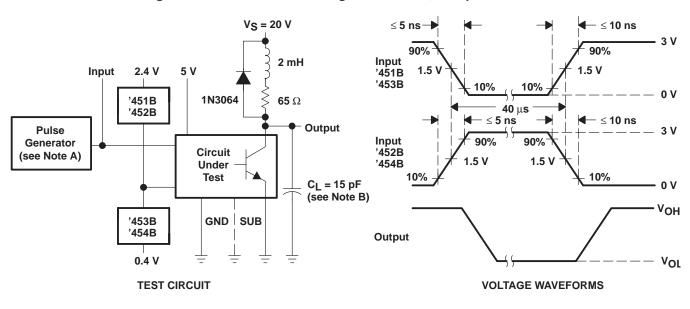


Figure 1. Test Circuit and Voltage Waveforms, Complete Drivers

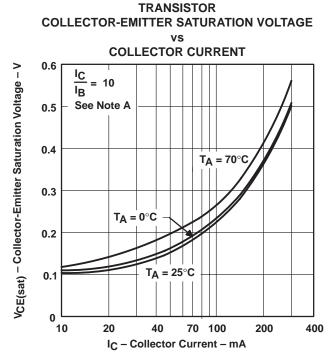
NOTES: A. The pulse generator has the following characteristics: PRR \leq 12.5 kHz, Z_O = 50 $\Omega.$ B. CL includes probe and jig capacitance.

Figure 2. Test Circuit and Voltage Waveforms for Latch-Up Test of Complete Drivers



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NOTE A: These parameters must be measured using pulse techniques, t_{W} = 300 µs, duty cycle $\leq 2\%.$

Figure 3



5-Jul-2005

PACKAGING INFORMATION

TEXAS INSTRUMENTS www.ti.com

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
5962-9563301Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	Level-NC-NC-NC
5962-9563301QPA	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	Level-NC-NC-NC
77049012A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	Level-NC-NC-NC
7704901PA	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	Level-NC-NC-NC
77049022A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	Level-NC-NC-NC
7704902PA	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	Level-NC-NC-NC
JM38510/12902BPA	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	Level-NC-NC-NC
JM38510/12903BPA	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	Level-NC-NC-NC
JM38510/12905BPA	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	Level-NC-NC-NC
SN55451BJG	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	Level-NC-NC-NC
SN55452BJG	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	Level-NC-NC-NC
SN55453BJG	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	Level-NC-NC-NC
SN55454BJG	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	Level-NC-NC-NC
SN75451BD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75451BDE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75451BDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75451BDRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75451BP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
SN75451BPSR	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75451BPSRE4	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75452BD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75452BDE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75452BDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75452BDRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75452BP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
SN75452BPSR	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75452BPSRE4	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75453BD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75453BDE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75453BDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

PACKAGE OPTION ADDENDUM

5-Jul-2005

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Packag Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	n MSL Peak Temp ⁽³⁾
SN75453BDRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75453BP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
SN75453BPSR	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75453BPSRE4	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75454BD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75454BDE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75454BDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75454BDRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75454BP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
SN75454BPE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
SN75454BPSR	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75454BPSRE4	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SNJ55451BFK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	Level-NC-NC-NC
SNJ55451BJG	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	Level-NC-NC-NC
SNJ55452BFK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	Level-NC-NC-NC
SNJ55452BJG	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	Level-NC-NC-NC
SNJ55453BFK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	Level-NC-NC-NC
SNJ55453BJG	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	Level-NC-NC-NC
SNJ55454BFK	OBSOLETE	LCCC	FK	20		TBD	POST-PLATE	Level-NC-NC-NC
SNJ55454BJG	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	Level-NC-NC-NC

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



PACKAGE OPTION ADDENDUM

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MECHANICAL DATA

MCER001A - JANUARY 1995 - REVISED JANUARY 1997



CERAMIC DUAL-IN-LINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification.
- E. Falls within MIL STD 1835 GDIP1-T8



MLCC006B - OCTOBER 1996

FK (S-CQCC-N**)

LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



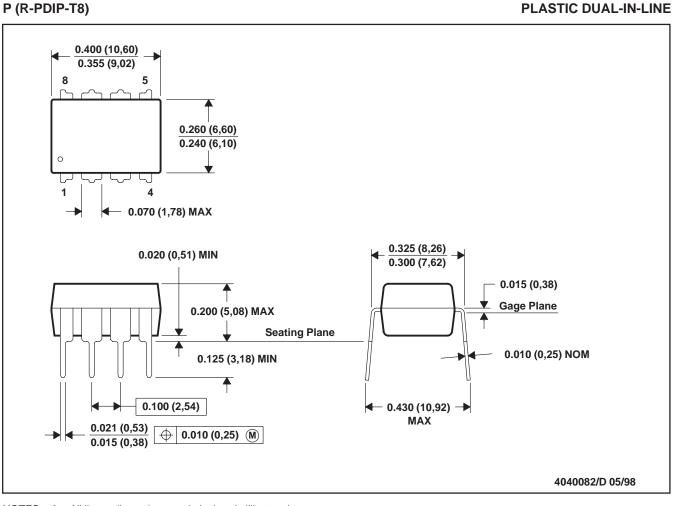
NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. The terminals are gold plated.
- E. Falls within JEDEC MS-004



MECHANICAL DATA

MPDI001A - JANUARY 1995 - REVISED JUNE 1999



- NOTES: A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MS-001

For the latest package information, go to http://www.ti.com/sc/docs/package/pkg_info.htm



D (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-012 variation AA.



MECHANICAL DATA

PS (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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